



## Low voltage NPN power transistor

Datasheet - production data

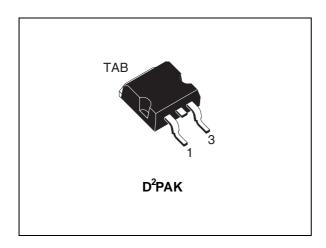
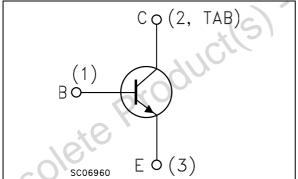


Figure 1. Internal schematic diagram



#### **Features**

- Low collector-emitter saturation voltage
- · Fast switching speed

#### **Applications**

- Power amplifier
- Switching circuits

#### **Description**

This device is an NPN transistor manufactured using new low voltage planar technology with double metal process. The result is a transistor which boasts exceptionally high gain performance coupled with very low saturation voltage.

Table 1. Device summary

Order codes	Marking	Package	Packaging
MJB44H11T4	MJB44H11	D <sup>2</sup> PAK	Tape and reel

# 1 Absolute maximum ratings

Table 2. Absolute maximum ratings

Symbol	Parameter	Value	Unit
$V_{CEO}$	Collector-emitter voltage (I <sub>B</sub> = 0)	80	V
V <sub>EBO</sub>	Emitter-base voltage (I <sub>C</sub> = 0)	5	V
I <sub>C</sub>	Collector current	10	А
I <sub>CM</sub>	Collector peak current	20	Α
P <sub>TOT</sub>	Total dissipation at T <sub>case</sub> = 25 °C	50	W
TSTG	Storage temperature	-55 to 150	°C
TJ	Max. operating junction temperature	150	°C

Table 3. Thermal data

•	Symbol	Parameter	Value	Unit	
	$R_{thJC}$	Thermal resistance junction-case max	2.5	°C/W	
	R <sub>thJA</sub>	Thermal resistance junction-ambient max	62.5	°C/W	
obsolet	e P'	oducils			

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## 2 Electrical characteristics

 $T_{case}$  = 25 °C; unless otherwise specified.

**Table 4. Electrical characteristics** 

Symbol	Parameter	Test conditions	Min.	Тур.	Max.	Unit
V <sub>CEO(sus)</sub> <sup>(1)</sup>	Collector-emitter sustaining voltage (I <sub>B</sub> = 0)	I <sub>C</sub> = 30 mA	80	-		V
I <sub>CES</sub>	Collector cut-off current (V <sub>BE</sub> = 0)	V <sub>CE</sub> = 80 V		-	10	μΑ
I <sub>EBO</sub>	Emitter cut-off current (I <sub>C</sub> = 0)	V <sub>EB</sub> = 5 V		10	50	μA
V <sub>CE(sat)</sub> <sup>(1)</sup>	Collector-emitter saturation voltage	I <sub>C</sub> = 8 A I <sub>B</sub> = 0.4 A	40	<u>Q-</u>	1	V
V <sub>BE(sat)</sub> <sup>(1)</sup>	Base-emitter saturation voltage	$I_C = 8 \text{ A}$ $I_B = 0.8 \text{ A}$		-	1.5	V
h <sub>FE</sub> <sup>(1)</sup>	DC current gain	$I_C = 2 A$ $V_{CE} = 1 V$	60	-		
	DO current gain	$I_C = 4 A$ $V_{CE} = 1 V$	40	-		

<sup>1.</sup> Pulse test: pulse duration ≤ 300 μs, duty cycle ≤ 2 %.

Electrical characteristics MJB44H11T4

## 2.1 Electrical characteristics (curves)

Figure 2. Safe operating area

Ic (A)

| Ic MAX | PULSE OPERATION | 100 µs | 10

Figure 3. Derating curve

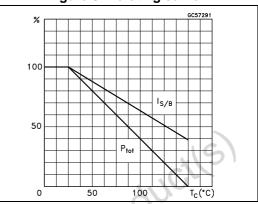
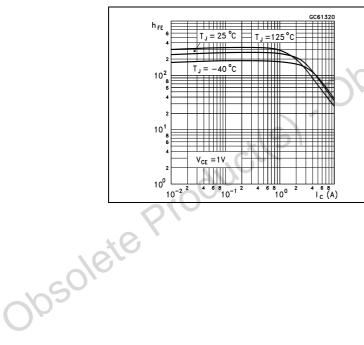
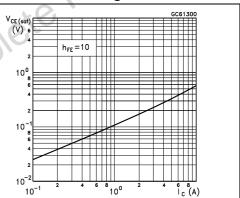


Figure 4. DC current gain

Figure 5. Collector-emitter saturation voltage





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## 3 Package mechanical data

In order to meet environmental requirements, ST offers these devices in different grades of ECOPACK<sup>®</sup> packages, depending on their level of environmental compliance. ECOPACK<sup>®</sup> specifications, grade definitions and product status are available at: <a href="https://www.st.com">www.st.com</a>. ECOPACK<sup>®</sup> is an ST trademark.

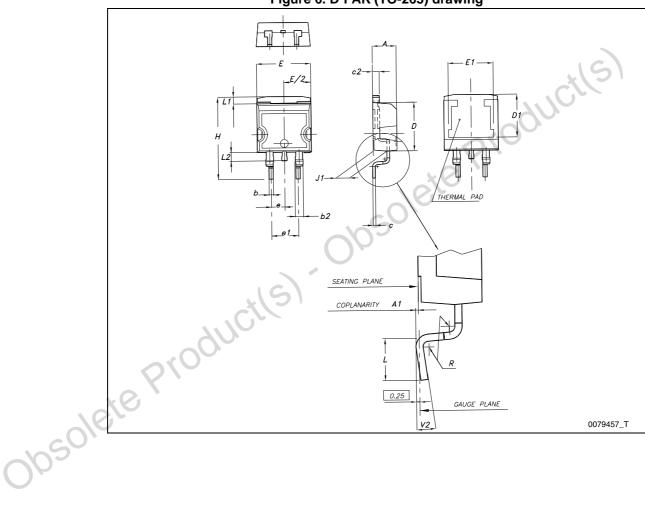
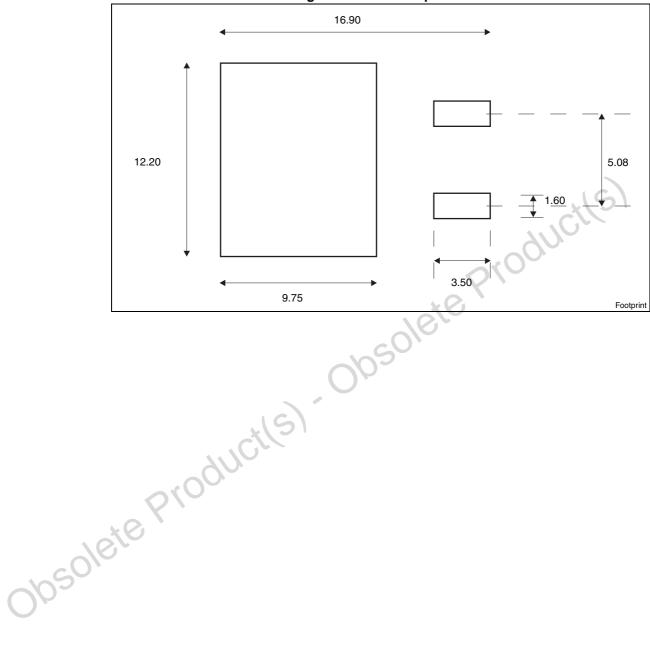


Figure 6. D<sup>2</sup>PAK (TO-263) drawing

Table 5. D<sup>2</sup>PAK (TO-263) mechanical data

	Dim	mm			
	Dim.	Min.	Тур.	Max.	
	А	4.40		4.60	
	A1	0.03		0.23	
	b	0.70		0.93	
	b2	1.14		1.70	
	С	0.45		0.60	
	c2	1.23		1.36	
	D	8.95		9.35	
	D1	7.50		90,	
	E	10		10.40	
	E1	8.50			
	е		2.54		
	e1	4.88		5.28	
	Н	15	W2	15.85	
	J1	2.49	) \	2.69	
	L	2.29		2.79	
	L1	1.27		1.40	
	L2	1.30		1.75	
	R	90.	0.4		
	V2	0°		8°	
opsolete	3				

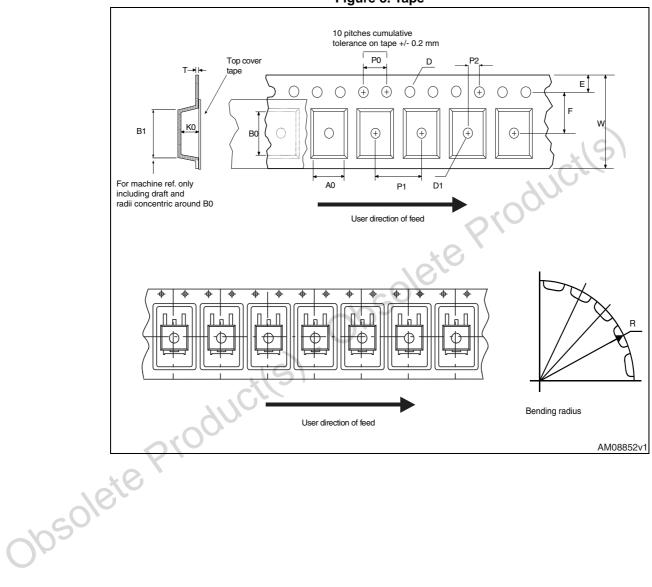
Figure 7. D<sup>2</sup>PAK footprint<sup>(a)</sup>



a. All dimension are in millimeters

## 4 Packaging mechanical data

Figure 8. Tape



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REEL DIMENSIONS 40mm min. Access hole At slot location В D С Tape slot in core for G measured at hub Full radius tape start 25 mm min. width AM08851v2

Figure 9. Reel

Table 6. D<sup>2</sup>PAK (TO-263) tape and reel mechanical data

Таре				Reel		
Dim.	mm		Dim.	mm		
Dim.	Min.	Max.	Dilli.	Min.	Max.	
A0	10.5	10.7	Α		330	
В0	15.7	15.9	В	1.5		
D	1.5	1.6	С	12.8	13.2	
D1	1.59	1.61	D	20.2		
Е	1.65	1.85	G	24.4	26.4	
F	11.4	11.6	N	100		
K0	4.8	5.0	Т		30.4	
P0	3.9	4.1				
P1	11.9	12.1		Base qty	1000	
P2	1.9	2.1		Bulk qty	1000	
R	50					
Т	0.25	0.35				
W	23.7	24.3	]			

Revision history MJB44H11T4

## 5 Revision history

**Table 7. Document revision history** 

	Date	Revision	Changes
	23-Jan-2012	1	Initial release.
	12-May-2014	2	Updated Section 3: Package mechanical data. Added Section 4: Packaging mechanical data.
005018	ste Prod	Notic	Added Section 4: Packaging mechanical data.

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